

2N6667

2N6667 Information

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Part Number	2N6667
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS PNP DARL 60V 10A TO220AB
Package	TO-220-3
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

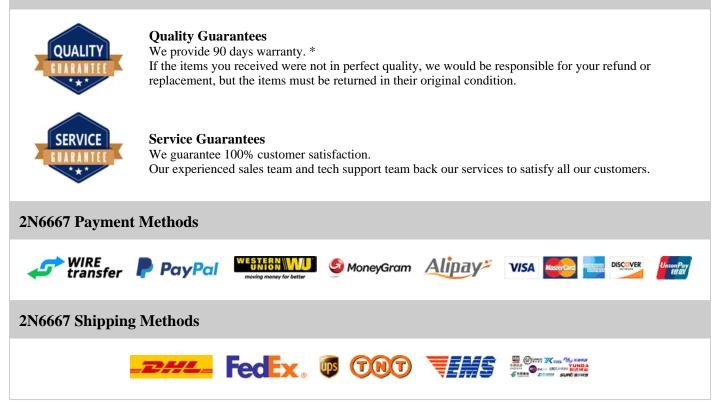
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2N6667 Specifications

Manufacturer Part Number	2N6667
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-220-3
Series	-
Transistor Type	PNP - Darlington
Current - Collector (Ic) (Max)	10A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	3V @ 100mA, 10A
Current - Collector Cutoff (Max)	1mA
DC Current Gain (hFE) (Min) @ Ic, Vce	1000 @ 5A, 3V
Power - Max	2W
Frequency - Transition	-
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	ТО-220-3
Supplier Device Package	TO-220AB
	Report errors?

2N6667 Guarantees



If you have any question about 2N6667, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com